### FEATURES

- Access time:55ns
- Low power consumption:
  Operating current: 10 mA (TYP.)
  Standby current: 1 μA (TYP)
- Single  $2.7V \sim 5.5V$  power supply
- Fully Compatible with all Competitors 5V product
- Fully Compatible with all Competitors 3.3V product
- Fully static operation
- Tri-state output
- Data retention voltage : 1.5V (MIN.)
- All products are ROHS Compliant
- Package: 32-pin 450 mil SOP

32-pin 600 mil P-DIP

32-pin 8mm x 20mm TSOP-I 32-pin 8mm x 13.4mm sTSOP 36-ball 6mm x 8mm TFBGA

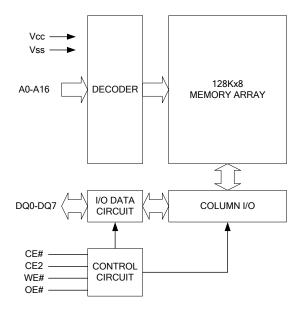
### GENERAL DESCRIPTION

The AS6C1008 is a 1,048,576-bit low power CMOS static random access memory organized as 131,072 words by 8 bits. It is fabricated using very high performance, high reliability CMOS technology. Its standby current is stable within the range of operating temperature.

The AS6C1008 is well designed for very low power system applications, and particularly well suited for battery back-up non-volatile memory application.

The AS6C1008 operates from a single power supply of  $2.7V \sim 5.5V$ .

#### FUNCTIONAL BLOCK DIAGRAM

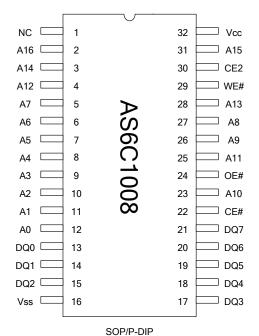


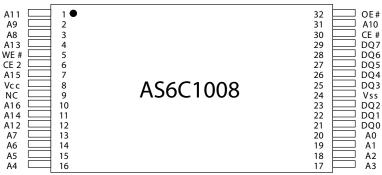
#### PIN DESCRIPTION

SYMBOL	DESCRIPTION
A0 - A16	Address Inputs
DQ0 – DQ7	Data Inputs/Outputs
CE#, CE2	Chip Enable Inputs
WE#	Write Enable Input
OE#	Output Enable Input
Vcc	Power Supply
Vss	Ground
NC	No Connection

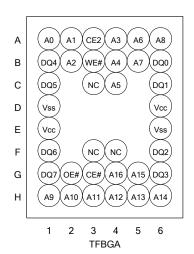


#### **PIN CONFIGURATION**





TS OP-I/sTSOP





# **ABSOLUTE MAXIMUM RATINGS\***

PARAMETER	SYMBOL	RATING	UNIT
Terminal Voltage with Respect to Vss	VTERM	-0.5 to 7.0	V
		0 to 70(C grade)	
Operating Temperature	TA		°C
		-40 to 85(I grade)	
Storage Temperature	Тѕтс	-65 to 150	°C
Power Dissipation	Po	1	W
DC Output Current	Іоит	50	mA
Soldering Temperature (under 10 sec)	Tsolder	260	°C

<sup>\*</sup>Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

## **TRUTH TABLE**

MODE	CE#	CE2	OE#	WE#	I/O OPERATION	SUPPLY CURRENT
Standby	Н	Х	Х	Х	High-Z	ISB1
Staridby	Х	L	Х	Х	High-Z	ISB1
Output Disable	L	Н	Н	Н	High-Z	Icc,Icc1
Read	L	Н	L	Н	Douт	Icc,Icc1
Write	L	Н	Х	L	Din	Icc,Icc1

Note: H = VIH, L = VIL, X = Don't care.

## **DC ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP. *4	MAX.	UNIT
Supply Voltage	Vcc		2.7	3.0	5.5	V
Input High Voltage	Vih*1		0.7*Vcc	-	Vcc+0.3	V
Input Low Voltage	V <sub>IL</sub> *2		- 0.2	-	0.6	V
Input Leakage Current	ILI	$Vcc \ge Vin \ge Vss$	- 1	-	1	μA
Output Leakage Current	ILO	$V_{CC} \ge V_{OUT} \ge V_{SS}$ , Output Disabled	- 1	-	1	μA
Output High Voltage	Vон	I <sub>OH</sub> = -1mA	2.2	2.7	-	V
Output Low Voltage	Vol	I <sub>OL</sub> = 2mA	-	-	0.4	V
Average Operating	lcc	Cycle time = Min. CE# = $V_{IL}$ and CE2 = $V_{IH}$ , - 55 $I_{I/O}$ = 0mA	-	10	60	mA
Power supply Current	ICC1	Cycle time = $1\mu$ s CE# $\leq$ 0.2V and CE2 $\geq$ Vcc-0.2V I <sub>I/O</sub> = 0mA other pins at 0.2V or Vcc-0.2V	_	1	10	mA
Standby Power	I <sub>SB1</sub>	CE# ≧V <sub>CC</sub> -0.2V C*	-	1	20	μA
Supply Current	1981	or CE2≦0.2V I*	-	1	50	μA

<sup>\*</sup>C=Commercial temperature/I= Industrial temperature



#### Notes:

- 1.  $V_{IH}(max) = V_{CC} + 3.0V$  for pulse width less than 10ns.
- 2. VIL(min) = Vss 3.0V for pulse width less than 10ns.
- 3. Over/Undershoot specifications are characterized, not 100% tested.
- 4. Typical values are included for reference only and are not guaranteed or tested. Typical valued are measured at Vcc = Vcc(TYP.) and T<sub>A</sub> = 25°C

### CAPACITANCE (TA = $25^{\circ}$ C, f = 1.0MHz)

PARAMETER	SYMBOL	MIN.	MAX	UNIT
Input Capacitance	Cin	-	6	pF
Input/Output Capacitance	Ci/o	-	8	pF

Note: These parameters are guaranteed by device characterization, but not production tested.

### **AC TEST CONDITIONS**

Input Pulse Levels	0.2V to Vcc - 0.2V
Input Rise and Fall Times	3ns
Input and Output Timing Reference Levels	1.5V
Output Load	C <sub>L</sub> =30pF + 1TTL, I <sub>OH</sub> /I <sub>OL</sub> = -1mA/2mA

## **AC ELECTRICAL CHARACTERISTICS**

### (1) READ CYCLE

PARAMETER	SYM.	AS6C1	AS6C1008-55		UNIT
		MIN.	MAX.		
Read Cycle Time	trc	55	-		ns
Address Access Time	taa	-	55		ns
Chip Enable Access Time	tace	-	55		ns
Output Enable Access Time	toe	-	30		ns
Chip Enable to Output in Low-Z	tcLz*	10	-		ns
Output Enable to Output in Low-Z	toLz*	5	-		ns
Chip Disable to Output in High-Z	tcHz*	-	20		ns
Output Disable to Output in High-Z	tonz*	-	20		ns
Output Hold from Address Change	tон	10	-		ns

## (2) WRITE CYCLE

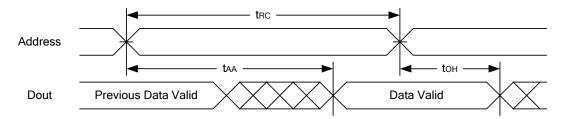
PARAMETER	SYM.	_	AS6C10	008-55	U	JNIT
			MIN.	MAX.		
Write Cycle Time	twc		55	-		ns
Address Valid to End of Write	taw		50	-		ns
Chip Enable to End of Write	tcw		50	-		ns
Address Set-up Time	tas		0	-		ns
Write Pulse Width	twp		45	-		ns
Write Recovery Time	twr		0	-		ns
Data to Write Time Overlap	tow		25	-		ns
Data Hold from End of Write Time	tон		0	-		ns
Output Active from End of Write	tow*		5	-		ns
Write to Output in High-Z	twnz*		-	20		ns

<sup>\*</sup>These parameters are guaranteed by device characterization, but not production tested.

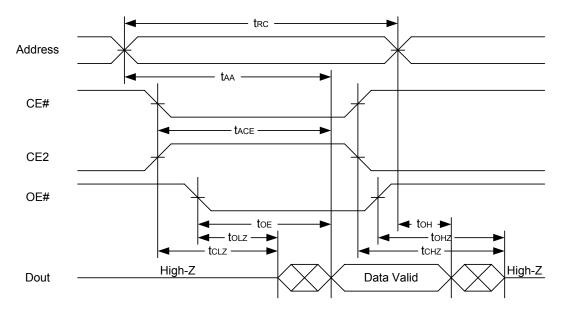


## **TIMING WAVEFORMS**

#### **READ CYCLE 1** (Address Controlled) (1,2)



#### READ CYCLE 2 (CE# and CE2 and OE# Controlled) (1,3,4,5)

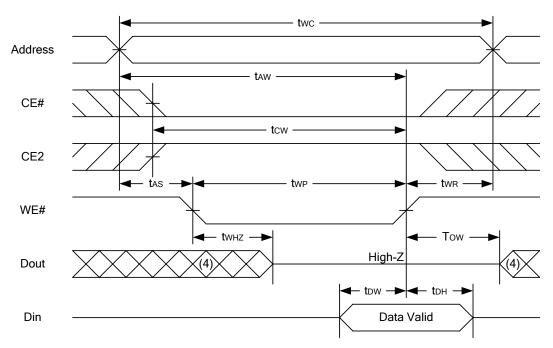


#### Notes:

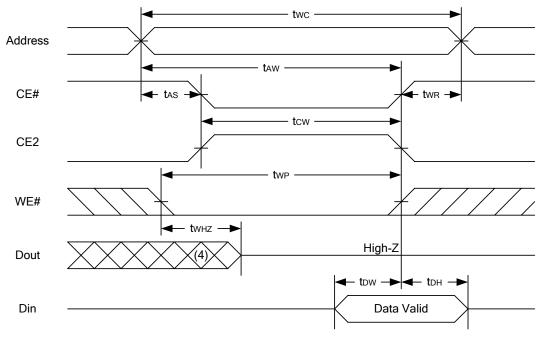
- 1.WE# is high for read cycle.
- 2.Device is continuously selected OE# = low, CE# = low., CE2 = high.
- 3.Address must be valid prior to or coincident with CE# = low, CE2 = high; otherwise tAA is the limiting parameter. 4.tclz, tclz, tchz and tohz are specified with CL = 5pF. Transition is measured ±500mV from steady state.
- 5.At any given temperature and voltage condition,  $t_{\text{CHZ}}$  is less than  $t_{\text{CLZ}}$ ,  $t_{\text{OHZ}}$  is less than  $t_{\text{OLZ}}$ .



#### WRITE CYCLE 1 (WE# Controlled) (1,2,3,5,6)



#### WRITE CYCLE 2 (CE# and CE2 Controlled) (1,2,5,6)



#### Notes:

- 1.WE#, CE# must be high or CE2 must be low during all address transitions.
- 2.A write occurs during the overlap of a low CE#, high CE2, low WE#.
- 3.During a WE#controlled write cycle with OE# low, twp must be greater than twHz + tpw to allow the drivers to turn off and data to be placed on the bus.
- 4. During this period, I/O pins are in the output state, and input signals must not be applied.
- 5.If the CE#low transition and CE2 high transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state.
- 6.tow and twHz are specified with  $C_L$  = 5pF. Transition is measured  $\pm 500mV$  from steady state.



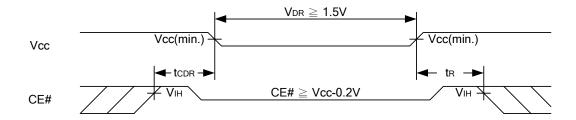
# **DATA RETENTION CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDI	TION	MIN.	TYP.	MAX.	UNIT
Vcc for Data Retention	1 1/00	$ \begin{array}{l} \text{CE\#} \geqq \text{V}_{\text{CC}} \text{- } 0.2\text{V} \\ \text{or CE2} \leqq 0.2\text{V} \end{array} $		1.5	1	5.5	V
Data Retention Current		Vcc = 1.5V CE# ≧ Vcc - 0.2V	C**	-	0.5	12	μΑ
Bata Retention ourient		or CE2 $\leq 0.2V$	<b> </b> **		0	30	μA
Chip Disable to Data Retention Time	tcdr	See Data Retentior Waveforms (below)		0	-	-	ns
Recovery Time	t <sub>R</sub>			t <sub>RC*</sub>	-	-	ns

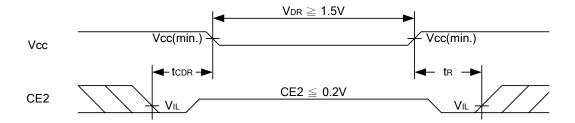
trc\* = Read Cycle Time C=Commercial temp/I = Industrial temp\*\*

### **DATA RETENTION WAVEFORM**

Low Vcc Data Retention Waveform (1) (CE# controlled)

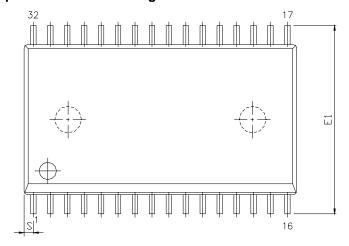


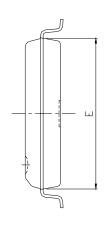
#### Low Vcc Data Retention Waveform (2) (CE2 controlled)

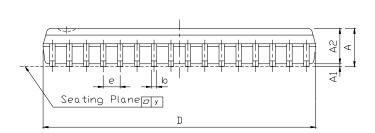


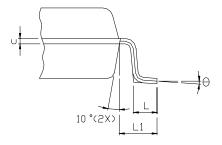
# **PACKAGE OUTLINE DIMENSION**

# 32 pin 450 mil SOP Package Outline Dimension



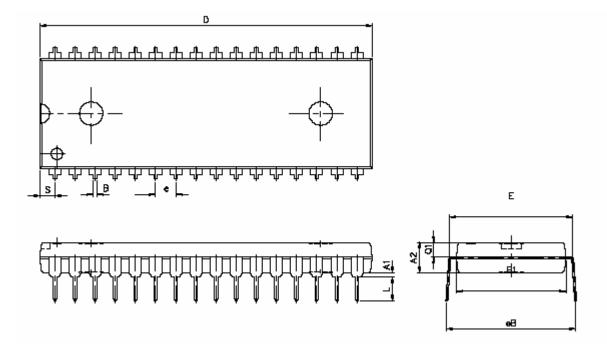






SYM. UNIT	INCH.(BASE)	MM(REF)
Α	0.118 (MAX)	2.997 (MAX)
A1	0.004(MIN)	0.102(MIN)
A2	0.111(MAX)	2.82(MAX)
b	0.016(TYP)	0.406(TYP)
С	0.008(TYP)	0.203(TYP)
D	0.817(MAX)	20.75(MAX)
Е	0.445 ±0.005	11.303 ±0.127
E1	0.555 ±0.012	14.097 ±0.305
е	0.050(TYP)	1.270(TYP)
L	0.0347 ±0.008	0.881 ±0.203
L1	0.055 ±0.008	1.397 ±0.203
S	0.026(MAX)	0.660 (MAX)
у	0.004(MAX)	0.101(MAX)
Θ	0° -10°	0° -10°

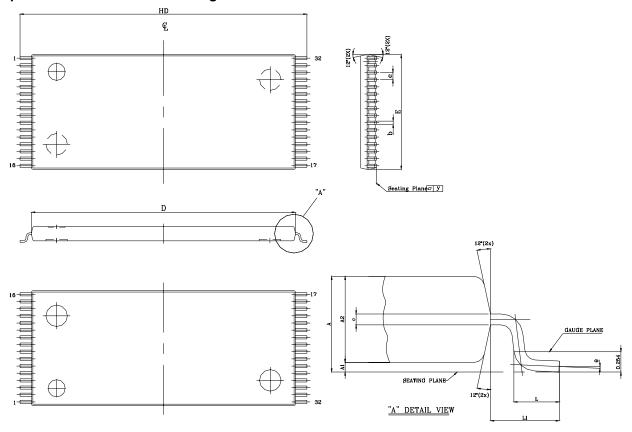
# 32 pin 600 mil P-DIP Package Outline Dimension



SYM. UNIT	INCH(BASE)	MM(REF)
A1	0.001 (MIN)	0.254 (MIN)
A2	$0.150 \pm 0.005$	3.810 ± 0.127
В	$0.018 \pm 0.005$	0.457 ± 0.127
D	$1.650 \pm 0.005$	41.910 ± 0.127
E	$0.600 \pm 0.010$	15.240 ± 0.254
E1	$0.544 \pm 0.004$	13.818 ± 0.102
e	0.100 (TYP)	2.540 (TYP)
eВ	$0.640 \pm 0.020$	16.256 ± 0.508.
L	$0.130 \pm 0.010$	$3.302 \pm 0.254$
S	$0.075 \pm 0.010$	1.905 ± 0.254
Q1	$0.070 \pm 0.005$	1.778 ± 0.127

Note: D/E1/S dimension do not include mold flash.

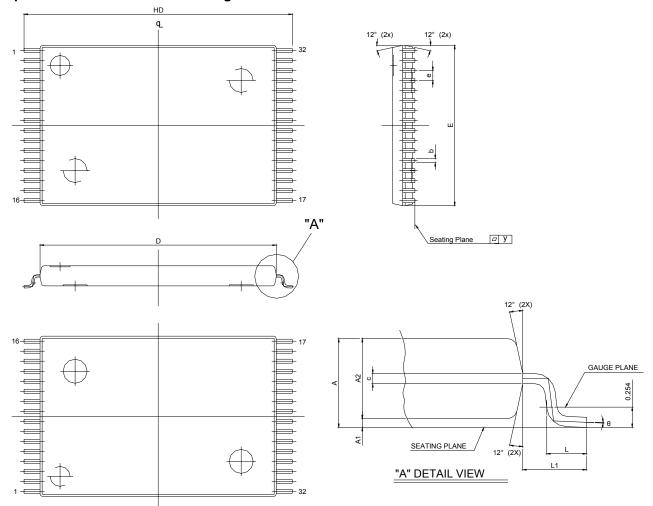
## 32 pin 8mm x 20mm TSOP-I Package Outline Dimension



SYM. UNIT	INCH(BASE)	MM(REF)
Α	0.047 (MAX)	1.20 (MAX)
A1	0.004 ±0.002	0.10 ±0.05
A2	0.039 ±0.002	1.00 ±0.05
b	0.008 + 0.002 - 0.001	0.20 + 0.05 -0.03
С	0.005 (TYP)	0.127 (TYP)
D	0.724 ±0.004	18.40 ±0.10
E	0.315 ±0.004	8.00 ±0.10
е	0.020 (TYP)	0.50 (TYP)
HD	0.787 ±0.008	20.00 ±0.20
L	0.0197 ±0.004	0.50 ±0.10
L1	0.0315 ±0.004	0.08 ±0.10
у	0.003 (MAX)	0.076 (MAX)
Θ	0°∼5°	0°∼5°



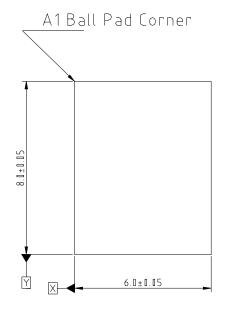
## 32 pin 8mm x 13.4mm sTSOP Package Outline Dimension

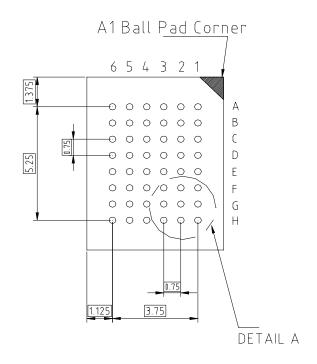


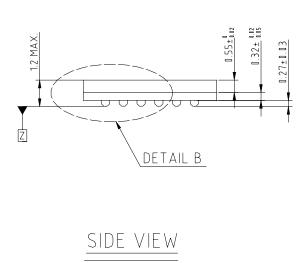
SYM. UNIT	INCH(BASE)	MM(REF)
Α	0.049 (MAX)	1.25 (MAX)
A1	0.005 ±0.002	0.130 ±0.05
A2	0.039 ±0.002	1.00 ±0.05
b	0.008 ±0.01	0.20±0.025
С	0.005 (TYP)	0.127 (TYP)
D	0.465 ±0.004	11.80 ±0.10
Е	0.315 ±0.004	8.00 ±0.10
е	0.020 (TYP)	0.50 (TYP)
HD	0.528±0.008	13.40 ±0.20.
L	0.0197 ±0.004	0.50 ±0.10
L1	0.0315 ±0.004	0.8 ±0.10
у	0.003 (MAX)	0.076 (MAX)
Θ	0°∼5°	0°∼5°

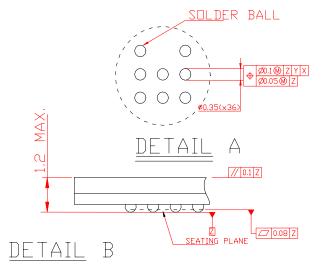


### 36 ball 6mm × 8mm TFBGA Package Outline Dimension











# **ORDERING INFORMATION**

# Ordering Codes

Alliance	Organization	VCC range	Package	Operating Temp	Speed ns
AS6C1008-55PCN	128K X 8	2.7-5.5V	32pin 600mil PDIP	Commercial ~ 0° C to 70° C	55
AS6C1008-55PIN	128K X 8	2.7-5.5V	32pin 600mil PDIP	Industrial ~ -40°C to 85° C	55
AS6C1008-55SIN	128K X 8	2.7-5.5V	32pin 450mil SOP	Industrial ~ -40°C to 85° C	55
AS6C1008-55TIN	128K X 8	2.7-5.5V	32pin TSOP-I (8 x 20 mm)	Industrial ~ -40°C to 85° C	55
AS6C1008-55STIN	128K X 8	2.7-5.5V	32pin sTSOP (8 x 13.4 mm)	Industrial ~ -40°C to 85° C	55
AS6C1008-55BIN	128K X 8	2.7-5.5V	36pin TFBGA (6mm x 8mm)	Industrial ~ -40°C to 85° C	55

# Part numbering system

AS6C	1008	- 55	Х	Х	N
	141		Package Options: P = 32 pin 600 mil P-DIP	Temperature Range:	
low	Device		S = 32 pin 450 mil SOP	C = Commercial	N = Lead
power	Number		T = 32 pin TSOP-I (8mm x 20 mm)	(0°C to +70° C)	Free ROHS
SRAM	10 = 1M	Access	ST = 32 pin sTSOP (8 x 13.4 mm)	I = Industrial	Compliant
prefix	08 = by 8	Time	B = 36 ball 6 x 8mm TFBGA	(-40° to +85° C)	Part

February 2007 AS6C1008

#### 128K X 8 BIT LOW POWER CMOS SRAM





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